

NDL5421P Series

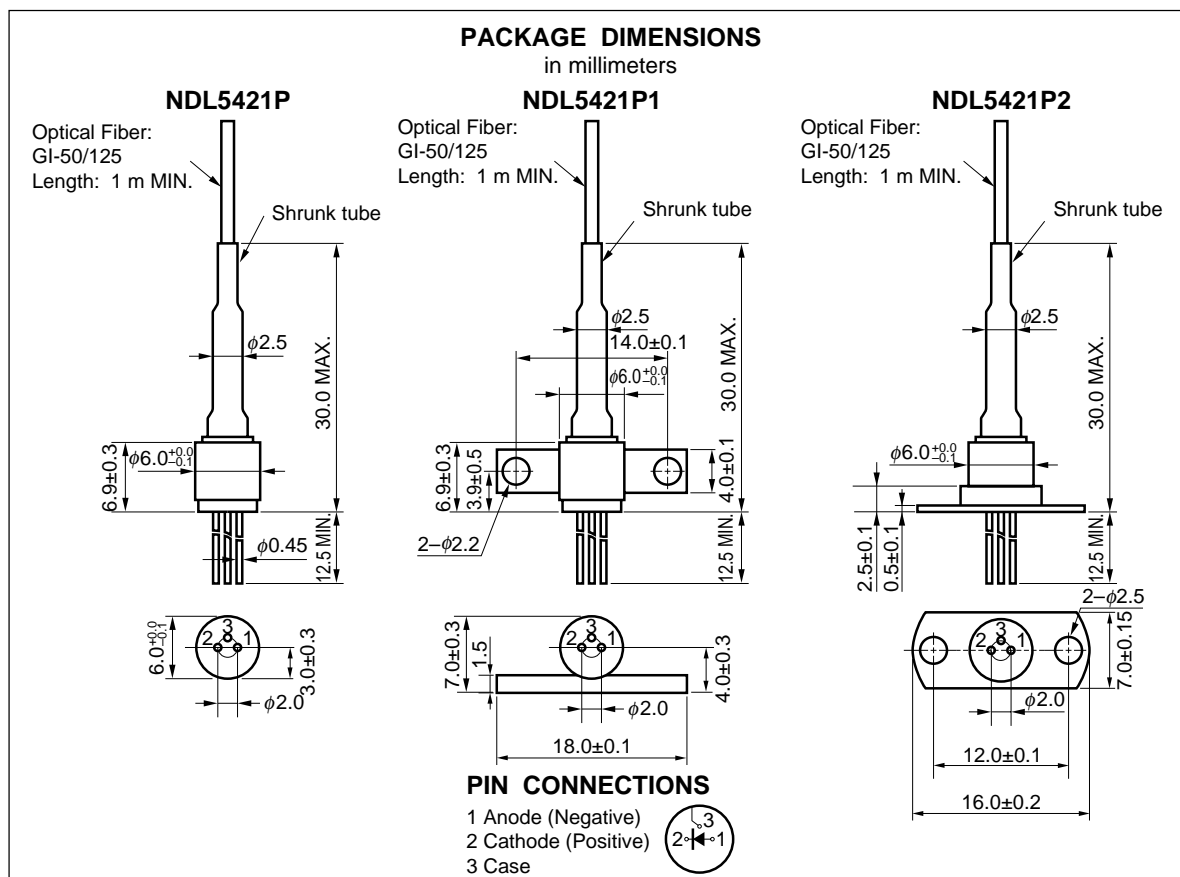
1 000 to 1 600 nm OPTICAL FIBER COMMUNICATIONS
 $\phi 50 \mu\text{m}$ InGaAs PIN PHOTO DIODE MODULE

DESCRIPTION

NDL5421P Series is an InGaAs PIN photo diode module with multimode fiber. It is designed for 2.5Gb/s optical fiber communication systems and covers the wavelength range between 1 000 and 1 600 nm with high efficiency.

FEATURES

- Small dark current $I_D = 0.1 \text{ nA}$
- High quantum efficiency $\eta = 86 \% @ \lambda = 1\,300 \text{ nm}$
 $\eta = 75 \% @ \lambda = 1\,550 \text{ nm}$
- Detecting area size $\phi 50 \mu\text{m}$
- Low operating voltage $V_R = 5 \text{ V}$
- Low terminal capacitance $C_t = 0.7 \text{ pF} @ f = 1.0 \text{ MHz}, V_R = 5 \text{ V}$
- High speed response $f_c = 2.5 \text{ GHz min.}$
- Coaxial module with multimode fiber (GI-50/125) or optional siglemode fiber (SM-9/125)



The information in this document is subject to change without notice.

★ ORDERING INFORMATION

Part Number	Available Connector	Description	
NDL5421P	Without Connector	GI-50/125	No Flange
NDL5421PC	With FC-PC Connector		
NDL5421PD	With SC-PC Connector		
NDL5421PS	Without Connector	SM-9/125	
NDL5421PSC	With FC-PC Connector		
NDL5421PSD	With SC-PC Connector		
NDL5421P1	Without Connector	GI-50/125	Flat Mount Flange
NDL5421P1C	With FC-PC Connector		
NDL5421P1D	With SC-PC Connector		
NDL5421P1S	Without Connector	SM-9/125	
NDL5421P1SC	With FC-PC Connector		
NDL5421P1SD	With SC-PC Connector		
NDL5421P2	Without Connector	GI-50/125	Vertical Flange
NDL5421P2C	With FC-PC Connector		
NDL5421P2D	With SC-PC Connector		
NDL5421P2S	Without Connector	SM-9/125	
NDL5421P2SC	With FC-PC Connector		
NDL5421P2SD	With SC-PC Connector		

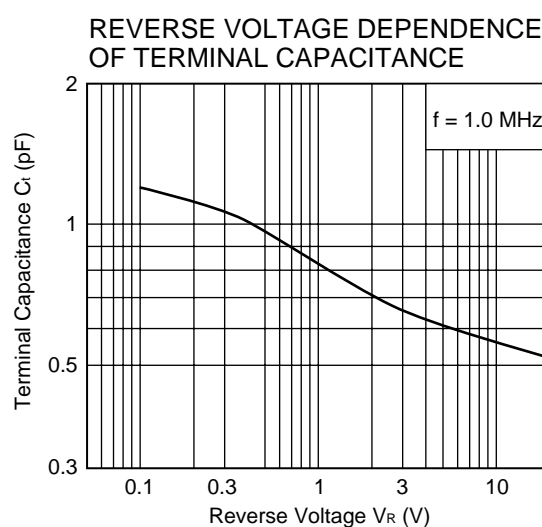
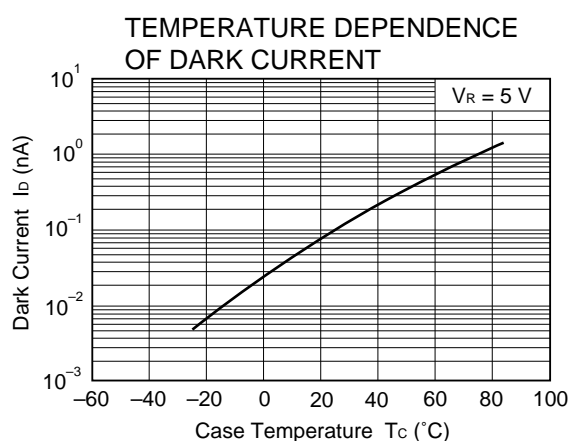
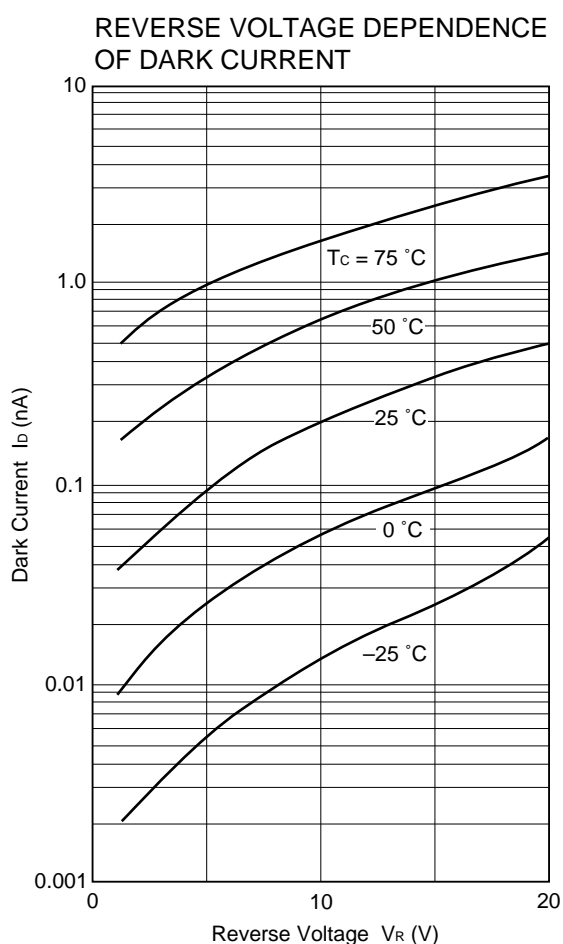
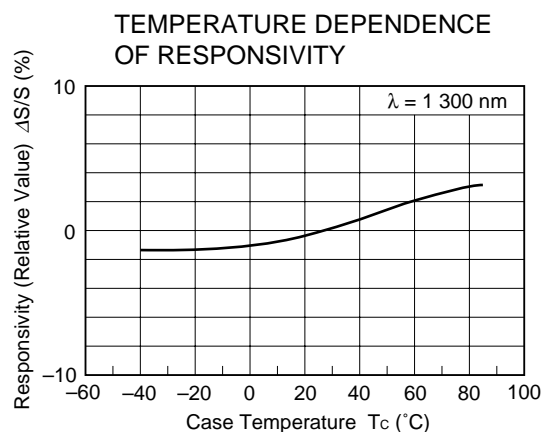
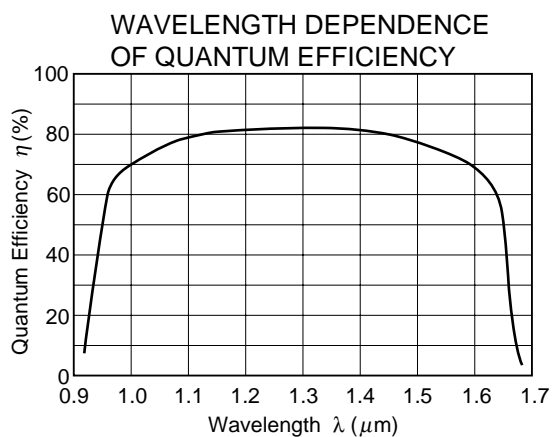
ABSOLUTE MAXIMUM RATINGS ($T_c = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

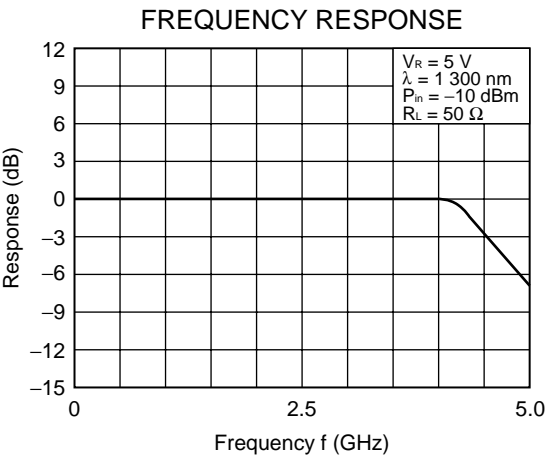
Parameter	Symbol	Ratings	Unit
Reverse Voltage	V_R	20	V
Forward Current	I_F	10	mA
Optical Input Power	P_{in}	8	mW
Operating Case Temperature	T_c	-40 to +85	$^{\circ}\text{C}$
Storage Temperature	T_{stg}	-40 to +85	$^{\circ}\text{C}$

ELECTRO-OPTICAL CHARACTERISTICS ($T_c = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Dark Current	I_D	$V_R = 5\text{ V}$		0.1	1.0	nA
Terminal Capacitance	C_t	$V_R = 5\text{ V}$, $f = 1.0\text{ MHz}$		0.7	0.9	pF
Quantum Efficiency	η	$\lambda = 1\ 300\text{ nm}$	75	86		%
		$\lambda = 1\ 550\text{ nm}$	64	75		
Responsivity	S	$\lambda = 1\ 300\text{ nm}$	0.78	0.89		A/W
		$\lambda = 1\ 550\text{ nm}$	0.80	0.94		
Cut-off Frequency	f_c	$V_R = 5\text{ V}$, $R_L = 50\ \Omega$, $\lambda = 1\ 300\text{ nm}$	2.5			GHz

TYPICAL CHARACTERISTICS ($T_c = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

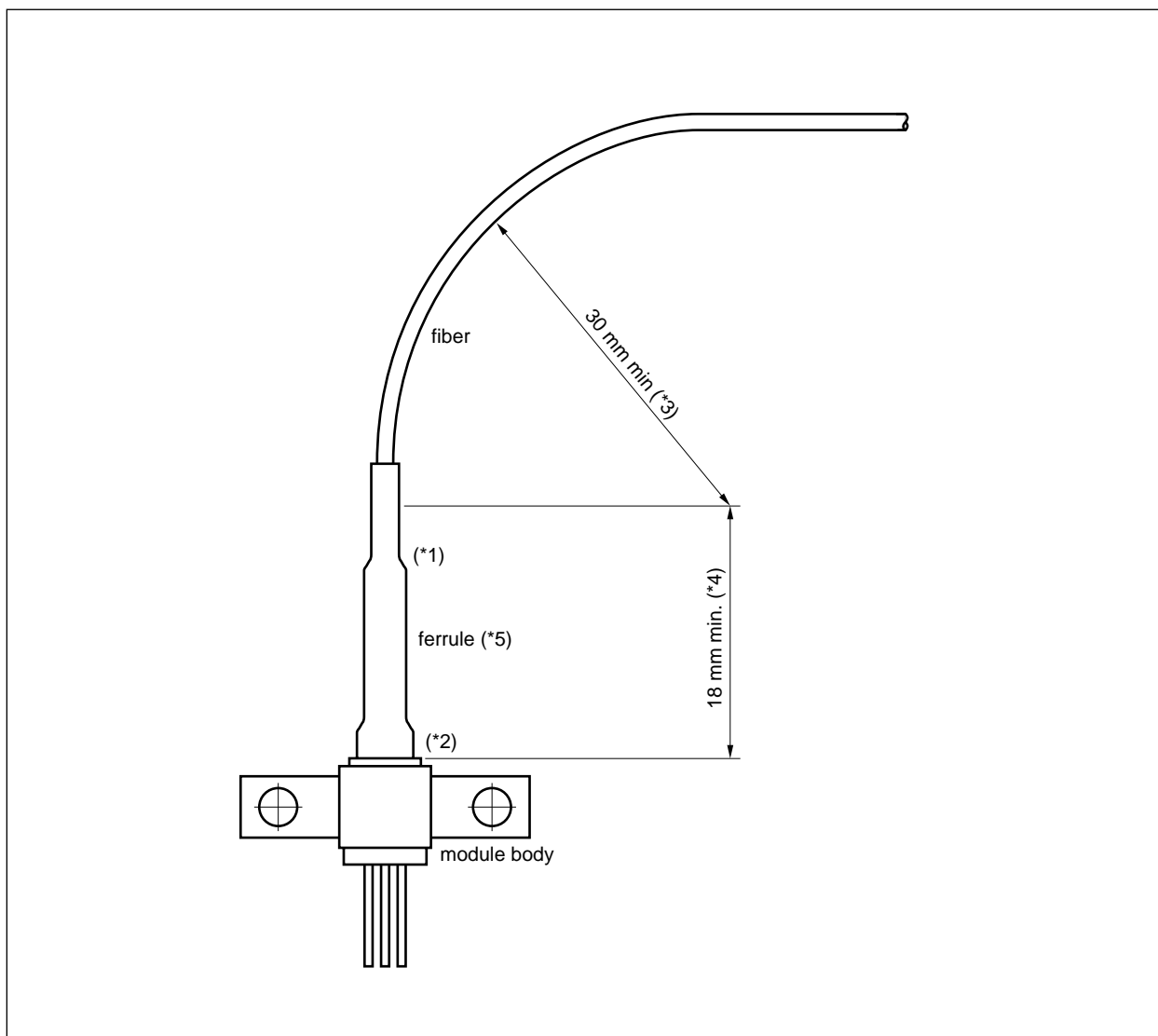




HANDLING PRECAUTION for PD/APD MODULE

The NEC PD/PAD module has heat shrink tubing to protect the ferrule edge (*1) and the junction between the ferrule and the module body (*2). In order to avoid breaking the fiber and/or optical coupling degradation, NEC recommends the following handling precautions.

1. Do not make the fiber bend radius less than 30 mm (*3).
2. Do not bend the fiber within the 18 mm section from the module body (*4).
3. Do not stress the ferrule with a lateral force exceeding 500 g (*5).



★ InGaAs APD/PD FAMILY

Features Packages	APD				PIN-PD		Remarks
	$\phi 30 \mu\text{m}$ (for 2.5 Gb/s)	$\phi 50 \mu\text{m}$ (for 2.5 Gb/s)	$\phi 50 \mu\text{m}$	$\phi 80 \mu\text{m}$	$\phi 50 \mu\text{m}$ (for 2.5 Gb/s)	$\phi 80 \mu\text{m}$	
TO-18 type Can	NDL5530	————	NDL5500	NDL5510	————	————	3 pins
TO-18 type Can with Micro Lens	————	————	————	————	NDL5490L ^{*3,4}	NDL5405L	3 pins
Small Can $\phi 5.6 \mu\text{m}$	NDL5531	————	————	————	NDL5490 ^{*3,4}	————	
Chip on Carrier	NDL5530C	NDL5520C	NDL5500C	NDL5510C	————	————	
Receptacle Module	————	————	————	————	————	NDL5471RC NDL5471RD	3 pins RC: FC receptacle RD: SC receptacle
Coaxial Module with MMF	————	NDL5521P NDL5521P1 NDL5521P2	NDL5551P NDL5551P1 NDL5551P2 NDL5553P ^{*1} NDL5553P1 ^{*1} NDL5553P2 ^{*1} NDL5590P NDL5590P1 NDL5590P2	NDL5561P ^{*2} NDL5561P1 ^{*2} NDL5561P2 ^{*2}	NDL5421P NDL5421P1 NDL5421P2	NDL5461P NDL5461P1 NDL5461P2	P1, P2: With flange NDL5590P Series: With Pre-AMP
Coaxial Module with SMF	NDL5531P NDL5531P1 NDL5531P2	————	NDL5553PS ^{*1} NDL5553P1S ^{*1} NDL5553P2S ^{*1}	————	————	NDL5481P ^{*5} NDL5481P1 ^{*5} NDL5481P2 ^{*5}	
14-pin DIP Module with TEC	————	————	NDL5506P NDL5506PS	————	————	————	$\Delta T = 45 \text{ K}$ (@ $I_c = 1.1 \text{ A}$) PS: With SMF
6-pin BFY Module with MMF	————	NDL5522P	————	————	NDL5422P	————	With Pre-AMP

*1 For OTDR

*2 With GI-62.5/125

*3 Under development

*4 Internal pre-amplifier for 1Gb/s

*5 For analog application (optical CATV)

Remark Modules are available with FC-PC connector or optional SC-PC connector.

REFERENCE

Document Name	Document No.
NEC semiconductor device reliability/quality control system	LEI-1201
Quality grade on NEC semiconductor devices	IEI-1209
Semiconductor device mounting technology manual	C10535E
Guide to quality assurance for semiconductor devices	MEI-1202
Semiconductor selection guide	X10679E

CAUTION

Within this device there exists GaAs (Gallium Arsenide) material which is a harmful substance if ingested. Please do not under any circumstances break the hermetic seal.

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NEC devices are classified into the following three quality grades:

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Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots

Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)

Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

The quality grade of NEC devices is "Standard" unless otherwise specified in NEC's Data Sheets or Data Books. If customers intend to use NEC devices for applications other than those specified for Standard quality grade, they should contact an NEC sales representative in advance.

Anti-radioactive design is not implemented in this product.